## G ate-controlled spin-splitting in quantum dots with ferrom agnetic leads in the K ondo regim e

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The e ect of a gate voltage  $(V_g)$  on the spin-splitting of an electronic level in a quantum dot (Q D) attached to ferror agnetic leads is studied in the K ondo regime using a generalized numerical renormalization group technique. We nd that the  $V_g$ -dependence of the Q D level spin-splitting strongly depends on the shape of the density of states (D O S). For one class of D O S shapes there is nearly no  $V_g$ -dependence, for another,  $V_g$  can be used to control the magnitude and sign of the spin-splitting, which can be interpreted as a local exchange magnetic eld. We nd that the spin-splitting acquires a new type of logarithm ic divergence. We give an analytical explanation for our numerical results and explain how they arise due to spin-dependent charge uctuations.

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The manipulation of magnetization and spin is one of the fundam ental processes in m agneto-electronics and spintronics, providing the possibility of writing inform ation in a magnetic memory [1], and also because of the possibility of classical or quantum computation using spin. In most situations this is realized by means of an externally applied, nonlocal magnetic eld which is usually di cult to insert into an integrated circuit. Recently, it was proposed to control the magnetic properties, such as the Curie tem perature of ferrom agnetic sem iconductors, by means of an electric eld: In gated structures [2], due to the modi cation of carrier-density-mediated magnetic interactions, such properties can be modied by a gate voltage. In this Letter we propose to control the am plitude and sign of the spin-splitting of a quantum dot (QD) induced by the presence of ferrom agnetic leads, only by using a gate voltage without further assistance of a magnetic eld. To illustrate this e ect we investigate the K ondo e ect and its spin-splitting as a very sensitive probe of the spin state of the dot and the e ective local magnetic eld in the QD generated by exchange interaction with the ferrom agnetic leads.

Recently, the possibility of the K ondo e ect in a QD attached to ferror agnetic electrodes was widely discussed [3, 4, 5, 6, 7, 8, 9], and it was shown, that the K ondo resonance is split and suppressed in the presence of ferrom agnetic leads [7, 8]. It was shown that this splitting can be compensated by an appropriately tuned external m agnetic eld, and the K ondo e ect is thereby restored [7, 8]. In all previous studies of QD s attached to ferrom agnetic leads [3, 4, 5, 6, 7, 8, 9] an idealized, at, spinindependent DOS with spin-dependent tunneling am plitudes was considered. How ever, since the spin-splitting arises from renorm alization e ects i.e. is a many-body effect, it depends on the fullDOS-structure of the involved material, and not only on its value at the Ferm i surface. In realistic ferrorm agnetic systems, the DOS shape is strongly asymmetric due to the Stoner splitting and the di erent hybridization between the electronic bands [1].

In this Letter we dem onstrate that the gate voltage dependence of the spin-splitting of a QD level, resulting in a splitting and suppression of the K ondo resonance, is determ ined by the DOS structure and can lead to crucially di erent behaviours. W e apply the num erical renorm alization group (NRG) technique extended to handle bands of arbitrary shape. For one class of DOS-shapes, we nd alm ost no V<sub>q</sub>-dependence of the spin-splitting, while for another class the induced spin-splitting, which can be interpreted as the e ect of a local exchange eld, can be controlled by V<sub>a</sub>. The spin-splitting can be fully com pensated and its direction can even be reversed within this class. We explain the physical mechanism that leads to this behavior, which is related to the compensation of the renorm alization of the spin-dependent QD levels induced by the electron-like and hole-like quantum charge uctuations. Moreover we nd that for the QD level close to the Ferm i surface, the amplitude of the spin-splitting has a logarithm ic divergence, indicating the many-body character of this phenom enon.

M odel and m ethod. { The Anderson m odel (AM ) of a single level Q D w ith energy  $_0$  and C oulom b interaction U, coupled to ferrom agnetic leads, is given by

$$H = \begin{array}{ccc} X & X \\ H = & {}_{rk} & C_{rk}^{V} & C_{rk} + {}_{0} & \hat{n} + U \hat{n}_{"} \hat{n}_{\#} \end{array}$$

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$$X + (V_{rk}d^{y}c_{rk} + hc:) BS_{z}:$$
(1)

Here  $c_{rk}$  and d ( $\hat{n} = d^y d$ ) are Fermi operators for electrons with momentum k and spin in the leads (r = L=R), and in the QD,  $V_{rk}$  is the tunneling am – plitude,  $S_z = (\hat{n}_* - \hat{n}_*)=2$ , and the last term denotes the Zeem an energy of the dot. The energy  $_0$  is experimentally controllable by  $V_g$  ( $_0$  '  $V_g$ ).

In order to discuss the gate voltage dependence of the QD level spin-splitting, we consider here a more realistic, both energy and spin dependent band structure  $[r_{r}(!) \notin r_{t}(!)]$ , violating p-h symmetry  $r(!) \# r_{t}(!)$ , which leads to an energy dependent hybridization function  $r(!) = (! \times )V_{rk}^{2} = r(!)V_{0}^{2}$ , where we take  $V_{rk} = V_{r}$  to be constant. We apply the NRG method [10, 11] extended to handle arbitrary DOS shapes and asymmetry. To this end, the standard logarithm ic discretization of the conduction band is performed for each spin component separately, with the bandwidths,  $D_{r} = D_{\#} = D_{0}$ , chosen such that the total spectral weight is included in  $[D_{0}; D_{0}]$  for all values of  $V_{g}$  studied here (to avoid di erent system atic errors upon changing  $V_{g}$ ).

W ithin each interval  $[!_n; !_{n+1}]$  and  $[!_{n+1};!_n]$ (with  $!_n = D_0$  <sup>n</sup>) of the logarithm ically discretized conduction band (CB) the operators of the continuous CB are expressed in terms of a Fourier series. Even though we allow for a non-constant conduction electron DOS, it is still possible to transform the Ham iltonian such that the impurity couples only to the zerostiag capterments com ponent of the Fourier expansion of each interval [12]. D ropping the non-constant Fourier-components of each interval [10, 11] then results in a discretized version of the Anderson model with the continous spectrum in each interval replaced by a single ferm ionic degree of freedom (independently for both spin directions). Since we allow for an arbitrary DOS for each spin com ponent (";#) of the CB this mapping needs to be performed for each separately. This leads to the Ham iltonian:

$$H = \hat{n} + U \hat{n}_{*} \hat{n}_{\#} + \frac{p}{0} = [d^{y} f_{0} + f_{0}^{y} d]$$

$$+ \prod_{n=0}^{K} f_{n}^{y} f_{n} + t_{n} (f_{n}^{y} f_{n+1} + f_{n+1}^{y} f_{n})]; (2)$$

where  $f_n$  are ferm ionic operators at the nth site of the W ilson chain,  $_0 = 1{=}2^{K_+D_0}_{D_0}$  (!)d!,  $t_n$  denotes the hopping matrix elements, and  $=_0$  B  $S_z$ . The absence of particle-hole symmetry leads to the appearance of non-zero on-site energies,  $"_n$  along the chain. In this general case no closed expression for the matrix elements  $t_n$  and  $"_n$ , both depending on the particular structure of the DOS via (!), is known, therefore they have to be determined recursively. This requires rather advanced numerical methods, due to the exponentially fast decay of  $t_n$  and  $"_n$  along the chain [13].

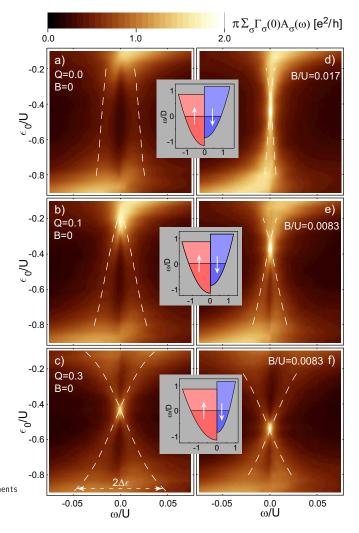


FIG.1: (color online).  $V_g$ -dependence of the spin-splitting: Normalized spectral function (0)A (!) as a function of energy ! and gate voltage 0, for the three di erent DOS shapes (depicted in insets) characterized by a di erent Q, which modi es both the spin and p-h asymmetry: (a-c) for magnetic led B = 0, (d) B=U = 0:017, (e), and (f) B=U = 0:0083. The white dashed lines are obtained using Eq. (3). Here U = 0:12D<sub>0</sub>,  $V_0^2$  = UD=6, = 0:15D and T = 0. Inset: the scheme of the parabolic DOS shape for spin " (red) and # (blue).

This method allows one to calculate the level occupation n hf i and the spin-resolved single-particle spectral density A (!) =  $\frac{1}{2} \text{ Im } G^r$  (!), where  $G^r$  (!) denotes a retarded G reen's function. For symmetric coupling [ $_L$  (!) =  $_R$  (!)] the spin-resolved conductance takes the form  $G = \frac{e^2}{h} \frac{R_{+1}}{1} d!$  (!) A (!) ( $\frac{@f(!)}{@!}$ ) where f(!) is the Fermi function.

Spectral function and conductance. { Here, we focus our attention on T = 0 properties. We have analyzed several types of DOS shapes and found three typical classes of the  $V_g$ -dependence of the K ondo resonance splitting. Since our method enables us to per-

form NRG calculations for arbitrary band-shapes, we decide to choose an example which turns out to encompass all three classes, namely  $(!) = \frac{1}{2}\frac{3}{8}^{2}D^{3=2}(1 + Q)^{1} + D +$ , where ! 2 [D; D],  $D_{0} = D + , [1(1) \text{ for " (#)]}$ , a square-root shape DOS equivalent to a parabolic band (as for free electrons) with Stoner splitting [14], and som e additional spin asymmetry Q, which modiles the amplitude of the DOS [see Fig. 1 (insets)].

In Fig. 1 we present the weighted spectral function A~(!) ể=h (0)A (!), normalized such that for  $! = 0 \pm \text{corresponds to the linear conductance G} = A^{(0)}$ as a function of energy ! and  $_0$ . We focus on a narrow energy window around the Ferm i surface where the K ondo resonance appears; charge resonances are visible when  $_{0}$  or U +  $_{0}$  approach the Ferm i surface, namely at energies  $_0=U$  > 0:1 or< 0:9. A Lthough the NRG method is designed to calculate equilibrium transport, one can still roughly deduce, from the spin-spitting afments the K ondo resonance of the equilibrium spectral function  $A^{\sim}(!)$ , the splitting of the zero-bias anomaly V in the non-equilibrium conductance G (V), since e V 2 [7]  $_{\widetilde{*}}$  is the splitting of the renorm alized levels). (  $\sim$ 

We present A (!) for three DOS shapes depicted in the insets of Fig. 1: (i) Q = 0 (a,d), (ii) Q = 0:1 (b,e), and (iii) Q = 0.3 (c,f), with 2 = 0.3D [15], leading to the three typical behaviors. Here the parameter Q tunes the spin and p-h asymmetry [see the de nition of (!)] resulting in di erent behaviours (for a detailed discussion see the last section). For (i) we nd nearly any  $_0$ -dependence of the spin-splitting; for (ii), a strong  $_0$ dependence without compensation of the spin-splitting (i.e. no crossing), and for (iii) a strong 0-dependence with a compensation (i.e. a crossing) and a change of the direction of the QD magnetization. The compensation (crossing) corresponds to the very peculiar situation where the K ondo e ect (strong coupling xed point) can be recovered in the presence of ferrom agnetic leads without any external magnetic eld. A behavior as presented in Fig. 1 (a,b) was recently observed experim entally [16, 17], where indeed a variation of the gate voltage results in two split conduction lines  $G(V;V_q)$  which are parallel for one case and converging for the other case, similar to our ndings.

E ect of a magnetic eld. { In Fig. 1(d,e,f) we show how a magnetic eld B modi es the results of Fig.1(a,b,c): in (i) the spin splitting can be compensated at a particular magnetic eld  $B_{com p}$  (here  $B_{com p}=U = 0.017$ ) and the K ondo e ect is visible in a wide range of 0; for (ii), at B=U = 0.0083, the K ondo e ect is recovered only at one particular 0-value, which depends on the applied magnetic eld; case (iii) shows that the crossing point shifts with B. Since  $B_{com p}$  can be viewed as a measure of the zero- eld splitting, (B = 0; 0) '  $B_{com p}$  (0), the 0-dependence of can be measured

G [e<sup>2</sup>/h] 1.0 0.0 20 <u>0.0</u> B/U 0.0 B/U 0.02 -0.02 0.02 0.04-0.02 0.04 a) Q=0.0 b) Q=0.1 0.0 \_0 -0.5 -1.0 -0.50 -0.45 -0.40 c) Q=0.3 0.0 1.0 <u>n = n<sub>↑</sub> + n</u> n 0.5 n 2 0.0  $m = n_{\uparrow} - n_{\downarrow}$ d) -0.5 -0.5 G [e<sup>2</sup>/h] e) Q=0.1 B/U=0.017 Q=0.3 B=0 -1.0 B/U=0.0083 -0.04 0.0 0.04 -1.0 -0.5 <sub>60</sub>/U 0.0 B/U

FIG.2: (color online). The QD's linear conductance G as a function of gate voltage  $_0$  and external magnetic eld B for the DOS shapes (a), (b), and (c) as for Fig.1(a), (b), and (c) respectively. (d) Spin-dependent occupancy n of the dot level as a function of gate voltage  $_0$  for the DOS shape as in Fig.1(c) and B = 0. (d) The  $_0$ -dependence of the total occupancy of the dot n and magnetization m for the situation from Fig.1(c). (e) The conductance G for the situations from Fig.1(c - dashed), (d - solid), and (f - long dashed). Parameters U, , and T as in Fig.1.

by studying that of  $B_{com p}$ , for which one needs to measure the linear conductance  $G(_0;B)$  as a function of both B and  $_0$ . In Fig. 2(a-c) we plot  $G(_0;B)$  for the three bands of Fig. 1. The two horizontal ridges (resonances) in Fig. 2(a-c) correspond to quantum charge uctuations (broadened QD level) of width . The lines with nite slope in Fig. 2(a-c) re ect the restored K ondo resonance and hence m ap out the  $_0$ -dependence of  $B_{com p}(_0) = (_0)$  when them agnetic eld com pensates the spin-splitting. Interestingly the spin-splitting and the corresponding  $B_{com p}$  tend to diverge (j j! 1) when approaching the charging resonance, as is best visible in Fig. 2(c).

Such a nite slope in  $G(_0;B)$  was observed for a singlet-triplet transition K ondo e ect in a two levelQD (Fig.2 (d) Ref. [18]). The corresponding transition leads to a characteristic maximum in the valley between two charging resonances (Fig.3 (c) Ref. [18]), similarly as in our Fig.2 (e). In that system the elective spin asymmetry (assumed by ourmodel) is realized by the asymmetry in the coupling of two QD levels [19].

In Fig. 2 (d) we show how the occupation n and the

m agnetic m om ent (spin) of the QD m =  $n_*$   $n_{\#} = 2hS_zi$ change as a function of  $_0$  for the situation of Fig. 1 (c). O ne nds that even though B = 0, it is possible to control the level spin-splitting of the QD, i.e. its spin, and thereby change the average spin direction of the QD from the parallel to anti-parallel alignment w.r.t. the lead's m agnetization. This opens the possibility of controlling the QD's spin state by m eans of a gate voltage w ithout further need of an external m agnetic eld, which is di cult to apply locally in practical devices.

Perturbative analysis. { One can understand the behavior presented in Fig. 1 (a-c) by using Haldane's scaling m ethod [20], where charge uctuations are integrated out. This leads to a spin-dependent renormalization of the QD's level position ~ and a level broadening . In contrast to Ref. [7] we consider here the case of nite C oulom b interactions U < 1, which m eans that also the doubly occupied state [21 is of importance. The spin-splitting is then given by " # + B, where

$$\frac{1}{2} d! \frac{(!)[I f(!)]}{!} + \frac{(!)f(!)}{!} + \frac{(!)f(!)}{!} :(3)$$

,

The rst term in the curly brackets corresponds to electron-like processes, namely charge uctuations between a single occupied state j i and the empty flione, and the second term to hole-like processes, namely charge uctuations between the states j i and 2i. The amplitude of the charge uctuations is proportional to , which T determ ines the width of QD's levels. Eq. (3) for shows that depends on the shape of (!) for all !, not only on its value at the Ferm i surface. The dashed lines in Fig. 1 (a-c) show as a function of  $_0$  [from Eq. (3)] for the same set of parameters as in the NRG calculation, and are in good agreement with the position of the (split) K ondo resonances observed in the latter. Eq. (3) shows that the dram atic changes observed in Fig.1 upon changing Q are due to the modi cation of the p-h and spin asymmetry.

Eq. (3) predicts that even for systems with spinasymmetric bands  $(!) \in (!)$ , the integral can give = 0, which corresponds to a situation where the renorm alization of due to electron-like processes are com pensated by hole-like processes. An example is a system consisting of p-h symmetric bands, (!) = (!), for which there is no splitting of the Kondo resonance = 0) for the symmetric point,  $_0$  = U=2. For ( real system s p-h sym m etric bands cannot be assum ed, how ever the compensation = 0 is still possible, as in Fig. 1 (c). Eq. (3) also shows that the characteristic energy scale of the spin-splitting is given by rather than by the Stoner splitting ( ), since the states far from the Ferm isurface enter Eq. (3) only with a logarithm ic weight. However, the Stoner splitting introduces a strong p-h asymmetry, so it can in uence the character of gate voltage dependence signi cantly.

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For a at band (!) = , Eq. (3) can be integrated analytically. For D<sub>0</sub> U,  $J_{0}^{*}$  jone nds: ' (P = ) Re[ (<sub>0</sub>) (U + <sub>0</sub>)], where P (<sub>" #</sub>)=, (x) ( $\frac{1}{2}$  +  $\frac{1}{2}\frac{x}{T}$ ), and (x) denotes the digam ma function. For T = 0, the spin-splitting is given by

$$' (P = ) \ln (j_0 j = j U + _0 j);$$
(4)

showing a logarithm ic divergence for  $_0$  ! 0 or U +  $_0$  ! 0. Since any su ciently smooth DOS can be linearized around the Ferm isurface, this logarithm ic divergence occurs quite universally, as can be observed in log-linear versions (not shown) of Fig. 2 (a-c). For nite temperature (T > 0) the logarithm ic divergence for  $_0$  ! 0 or  $_0$  ! U is cut o , '  $\frac{1}{2}$ P [ ( $\frac{1}{2}$ ) +  $\ln \frac{2}{U}$ ], which is also in portant for temperatures T  $T_K$ .

In conclusion, we demonstrated, using the extended NRG technique for general band shapes, the possibility of controlling the local exchange eld and thereby the spin-splitting in a QD attached to ferrom agnetic leads by m eans of the gate voltage. A new type of the logarithm ic divergence of the QD's level spin-splitting was found, and attributed to spin-dependent charge uctuations.

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